

STRUCTURE AND FABRICATION OF DEVICE, SUCH AS
LIGHT-EMITTING DEVICE OR ELECTRON-EMITTING DEVICE,
HAVING GETTER REGION

By

5 Christopher J. Curtin,
Duane A. Haven,
Theodore S. Fahlen,
George B. Hopple,
Lawrence S. Pan,
10 Igor L. Maslennikov,
Michael J. Nystrom,
Jun Gordon Liu,
Randolph S. Gluck,
Tomoo Kosugi,
15 James C. Dunphy, and
David L. Morris

ABSTRACT

20 A light-emitting device is provided with getter
material (58) that can readily be distributed in a
relatively uniform manner across the device's active
light-emitting portion. An electron-emitting device is
similarly provided with getter material (112, 110/112,
128, 132, and 142) that can readily be distributed
25 relatively uniformly across the active electron-
emitting portion of the device. Techniques such as
thermal spraying, angled physical deposition, and
maskless electrophoretic/dielectrophoretic deposition
can be utilized in depositing the getter material.